CATV Amplifier Module

Features

- · Specified for 6- and 10-Channel Loading
- **Excellent Distortion Performance**
- Low Power Consumption
- Capable of Handling Multiple Channels in the Return Path with Good Distortion Performance
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

- CATV Systems Operating in the 5 to 65 MHz Frequency Range
- Specified for Use as a Return Path Amplifier for Low-Split 2-Way Cable TV Systems

Description

• 24 Vdc Supply, 5 to 65 MHz, CATV Reverse Amplifier Module

MHW1224LA

5-65 MHz, 22.7 dB, 10-CHANNEL **CATV LOW CURRENT AMPLIFIER MODULE**

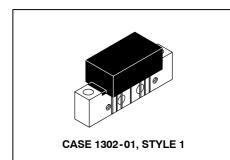


Table 1. Maximum Ratings

Parameter	Symbol	Value	Unit	
DC Supply Voltage	V _{CC}	+28	Vdc	
RF Input Voltage (Single Tone)	V _{in}	+60	dBmV	
Operating Case Temperature Range	T _C	- 20 to +100	°C	
Storage Temperature Range	T _{stg}	- 40 to +100	°C	

Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = 30°C, 75 Ω system, unless otherwise noted)

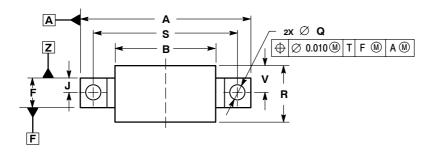
Characteristic		Symbol	Min	Тур	Max	Unit
Bandwidth	All	BW	5	_	65	MHz
Power Gain	(f = 5 MHz)	G _p	22.1	22.7	23.2	dB
Slope (5-65 MHz)		S	- 0.2	_	0.5	dB
Gain Flatness (Peak To Valley)	(5-65 MHz)	G _F	=	_	0.4	dB
Return Loss — Input/Output	(@ f = 5-65 MHz)	IRL/ORL	20	_	_	dB
Composite Second Order (V _{out} = +50 dBmV per Ch., Worst Case)						dBc
	6-Channel FLAT 10-Channel FLAT	CSO ₆ CSO ₁₀		- 73 - 72	- 68 - 65	

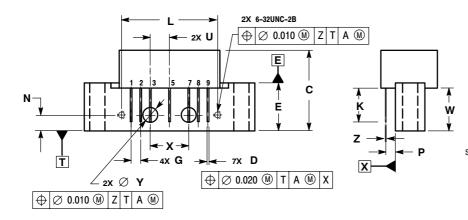
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = 30°C, 75 Ω system, unless otherwise noted) (continued)

Characteristic	Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion					dBc
(V _{out} = +50 dBmV per Ch., Worst Case)					
6-Channel FLAT	XMD_6	_	- 69	- 65	
10-Channel FLAT	XMD ₁₀	_	- 63	- 60	
Composite Triple Beat					dBc
(V _{out} = +50 dBmV per Ch., Worst Case)					
6-Channel FLAT	CTB ₆	_	- 78	- 75	
10-Channel FLAT	CTB ₁₀	_	- 69	- 66	
Noise Figure	NF				dB
(f = 5-65 MHz)		_	6.3	7	
DC Current	I _{DC}	85	95	110	mA

ARCHIVE INFORMATION

PACKAGE DIMENSIONS





	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α		1.775		45.085
В		1.085		27.559
С		0.840		21.336
D	0.015	0.021	0.381	0.533
E	0.465	0.510	11.811	12.954
F	0.300	0.325	7.62	8.255
G	0.100 BSC		2.540 BSC	
7	0.156 BSC		3.962 BSC	
K	0.315	0.355	8.001	9.017
L	1.000 BSC		25.400 BSC	
N	0.165	BSC	4.191 BSC	
P	0.100 BSC		2.540 BSC	
Q	0.148	0.168	3.759	4.267
R		0.600		15.24
S	1.500 BSC		38.100 BSC	
U	0.200 BSC		5.080 BSC	
٧		0.250		6.350
W	0.435		11.049	
X	0.400 BSC		10.160 BSC	
Υ	0.152	0.163	3.861	4.140
Z	0.009	0.011	0.229	0.279

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01 ISSUE B

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